Triple SPDT 1.0 Ω R_{ON} Switch

The NLAS4783B is a triple independent low R_{ON} SPDT analog switch with ENABLE. This device is designed for low operating voltage, high current switching of speaker output for cell phone applications. It can switch a balanced stereo output. The NLAS4783B can handle a balanced microphone/speaker/ring-tone generator in a monophone mode. The device contains a break-before-make feature.

Features

- Single Supply Operation
 1.65 to 4.5 V V_{CC}
 Function Directly from LiON Battery
- Tiny 3 x 3 mm 16-Pin QFN Package
 Meets JEDEC MO-220 Specifications
- Low Static Power
- OVT on Logic Address and Enable Inputs
- This is a Pb-Free Device*

Typical Applications

- Cell Phone Speaker/Microphone Switching
- Ringtone-Chip/Amplifier Switching
- Three Unbalanced (Single-Ended) Switches
- Stereo Balanced (Push-Pull) Switching

Important Information

• ESD Protection:

Human Body Model (HBM) > 8000 V Machine Model (MM) > 400 V

- Ringtone-Chip/Amplifier Switching
- Continuous Current Rating Through each Switch ±300 mA
- Conforms to: JEDEC MO-220, Issue H, Variation VEED-6
- Pin-for-Pin Compatible with MAX4783



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MARKING DIAGRAM



QFN-16 CASE 485AE



A = Assembly Location

L = Wafer Lot

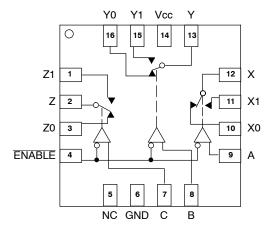
Y = Year

W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

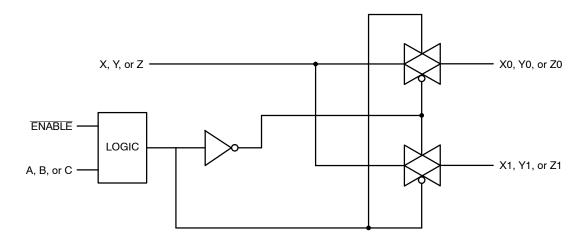


Figure 1. Input Equivalent Circuit

PIN FUNCTION DESCRIPTION

QFN PIN #	Symbol	Description
15	Y1	Analog Switch Y Normally Open Input
16	Y0	Analog Switch Y Normally Closed Input
1	Z1	Analog Switch Z Normally Open Input
2	Z	Analog Switch Z Output
3	Z0	Analog Switch Z Normally Closed Input
4	ENABLE	Digital Enable Input. Normally connect to GND. Drive to logic high to set all switches off.
5	NC	No Connection. Not internally connected.
6	GND	Ground
7	С	Digital Address C Input
8	В	Digital Address B Input
9	Α	Digital Address A Input
10	X0	Analog Switch X Normally Closed Input
11	X1	Analog Switch X Normally Open Input
12	Х	Analog Switch X Output
13	Υ	Analog Switch Y Output
14	V _{CC}	Positive Analog and Digital Supply Voltage Input

TRUTH TABLE/SWITCH PROGRAMMING

		Select Input		
Enable Input	С	В	Α	
н	х	Х	х	All Switches Open
L	L	L	L	X–X0 Y–Y0 Z–Z0
L	L	L	н	X-X1 Y-Y0 Z-Z0
L	L	Н	L	X-X0 Y-Y1 Z-Z0
L	L	Н	н	X–X1 Y–Y1 Z–Z0
L	н	L	L	X–X0 Y–Y0 Z–Z1
L	н	L	н	X–X1 Y–Y0 Z–Z1
L	н	Н	L	X–X0 Y–Y1 Z–Z1
L	н	Н	н	X-X1 Y-Y1 Z-Z1

^{1.} Input and output pins are identical and interchangeable. Both pins can be considered input or output. Bidirectional signal pass.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Positive DC Supply Voltage	-0.5 to +5.5	V
V _{IS}	Analog Input Voltage (V _{NO} , V _{NC} , or V _{COM})	– 0.5 to V _{CC}	V
V _{IN}	Digital Select Input Voltage	-0.5 to +5.5	V
I _{anl1}	Continuous DC Current from COM to NC/NO	±300	mA
I _{anl-pk 1}	Peak Current from COM to NC/NO, 10 Duty Cycles (Note 2)	±500	mA
I _{clmp}	Continuous DC Current into COM/NC/NO with Respect to V _{CC} or GND	±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
2. Defined as 10% ON, 90% off duty cycle.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
V _{CC}	Positive DC Supply Voltage	1.65	4.5	V	
V _{IS}	Analog Input Voltage (V _{NO} , V _{NC} , or V _{COM})	-	V _{CC}	V	
V _{IN}	Digital Select Input Voltage	-	V _{CC}	V	
T _A	Operating Temperature Range	-40	85	°C	
t _r , t _f	Input Rise or Fall Time, SELECT	V _{CC} = 1.6-2.7 V V _{CC} = 3.0-4.5 V	-	20 10	ns/V

DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

				Guarante	ed Limit	
Symbol	Parameter	Condition	V _{CC}	-40°C to 25°C	<85°C	Unit
V _{IH}	Minimum High-Level Input Voltage, Select Inputs		1.65 2.7 3.6 4.3	1.0 1.4 1.8 2.2	1.0 1.4 1.8 2.2	V
V _{IL}	Maximum Low-Level Input Voltage, Select Inputs		1.65 2.7 3.6 4.3	0.4 0.5 0.6 0.8	0.4 0.5 0.6 0.8	V
I _{IN}	Maximum Input Leakage Current, Select Inputs	V _{IN} = 4.5 V or GND	4.3	± 0.1	± 1.0	μΑ
I _{OFF}	Power Off Leakage Current	V _{IN} = 4.5 V or GND	0	±0.5	±2.0	μΑ
Icc	Maximum Quiescent Supply Current (Note 3)	Select and V _{IS} = V _{CC} or GND	1.65 to 4.5	± 1.0	± 2.0	μА

DC ELECTRICAL CHARACTERISTICS - Analog Section

				Guara	inteed Ma	aximum	Limit	
				-40°C	to 25°C	<8	5°C	1
Symbol	Parameter	Condition	V _{CC}	Min	Max	Min	Max	Unit
R _{ON}	NC/NO On-Resistance (Note 3)	$\begin{aligned} &V_{IN} \leq V_{IL} \text{ or } V_{IN} \geq V_{IH} \\ &V_{IS} = \text{GND to } V_{CC} \\ &I_{IN}I \leq 100 \text{ mA} \end{aligned}$	2.7 - 4.3		1.0		1.2	Ω
R _{FLAT}	NC/NO On–Resistance Flatness (Notes 3, 5)	$I_{COM} = 100 \text{ mA}$ $V_{IS} = 0 \text{ to } V_{CC}$	2.7 – 4.3		0.2		0.2	Ω
ΔR_{ON}	On-Resistance Match Between Channels (Notes 3 and 4)	$V_{IS} = 0.5 V_{CC};$ $I_{COM} = 100 \text{ mA}$	2.7 – 4.3		0.4		0.6	Ω
I _{NC(OFF)} I _{NO(OFF)}	NC or NO Off Leakage Current (Note 3)	$ \begin{aligned} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} &= 0.3 \text{ V} \\ V_{COM} &= 4.0 \text{ V} \end{aligned} $	4.3	-10	10	-100	100	nA
I _{COM(ON)}	COM ON Leakage Current (Note 3)	$\begin{split} &V_{IN} = V_{IL} \text{ or } V_{IH} \\ &V_{NO} \text{ 0.3 V or 4.0 V with} \\ &V_{NC} \text{ floating or} \\ &V_{NC} \text{ 0.3 V or 4.0 V with} \\ &V_{NO} \text{ floating} \\ &V_{COM} = \text{ 0.3 V or 4.0 V} \end{split}$	4.3	-10	10	-100	100	nA

Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
 ΔR_{ON =} R_{ON(MAX)} - R_{ON(MIN)} between NC1 and NC2 or between NO1 and NO2.
 Flatness is defined as the difference between the maximum and minimum value of on–resistance as measured over the specified analog signal ranges.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

					Guaranteed Maximum Limit					
			V _{cc}	V _{IS}	-40	-40°C to 25°C		<85°C		
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур*	Max	Min	Max	Unit
t _{ON}	Turn-On Time	$R_L = 50 \Omega$, $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 4.5	1.5			25		27	ns
t _{OFF}	Turn-Off Time	$R_L = 50 \Omega$, $C_L = 35 pF$ (Figures 3 and 4)	2.3 – 4.5	1.5			15		20	ns
t _{BBM}	Minimum Break-Before-Make Time	$V_{IS} = 3.0$ $R_L = 300 \ \Omega, \ C_L = 35 \ pF$ (Figure 2)	3.0	1.5	2.0	8.0				ns

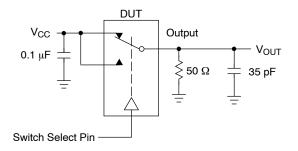
		Typical @ 25, V _{CC} = 4.5 V	
C _{IN}	Control Pin Input Capacitance	5.0	pF
C _{SN}	SN Port Capacitance	75	pF
C _D	D Port Capacitance When Switch is Enabled	240	pF

^{*}Typical Characteristics are at 25°C.

ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			V _{CC}	25°C	
Symbol	Parameter	Condition	(V)	Typical	Unit
BW	Maximum On-Channel -3dB Bandwidth or Minimum Frequency Response	V _{IN} centered between V _{CC} and GND (Figure 5)	1.65 – 4.5	17	MHz
V _{ONL}	Maximum Feed-through On Loss	V_{IN} = 0 dBm @ 100 kHz to 50 MHz V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 4.5	-0.10	dB
V _{ISO}	Off-Channel Isolation	f = 100 kHz; V_{IS} = 1 V RMS; C_L = 5 nF V_{IN} centered between V_{CC} and GND(Figure 5) (Note 6)	1.65 – 4.5	-62	dB
Q	Charge Injection Select Input to Common I/O	$V_{IN} = V_{CC \text{ to}} \text{ GND, } R_{IS} = 0 \Omega, C_L = 1 \text{ nF}$ Q = C _L x ΔV_{OUT} (Figure 6)	1.65 – 4.5	50	рС
THD	Total Harmonic Distortion THD + Noise	F_{IS} = 20 Hz to 20 kHz, R_L = R_{gen} = 600 Ω , C_L = 50 pF V_{IS} = 2 V RMS	4.5	0.008	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; V_{IS} = 1 V RMS, C_L = 5 pF, R_L = 50 Ω V_{IN} centered between V_{CC} and GND (Figure 5)	1.65 – 4.5	-62	dB

^{6.} Off-Channel Isolation = 20log10 (Vcom/Vno), Vcom = output, Vno = input to off switch.



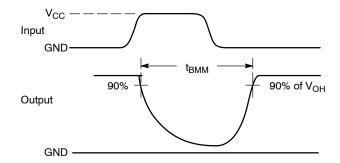
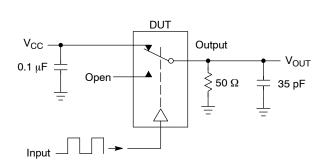


Figure 2. t_{BBM} (Time Break-Before-Make)



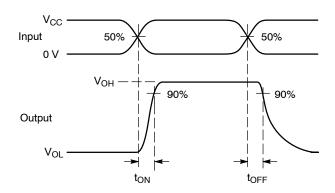
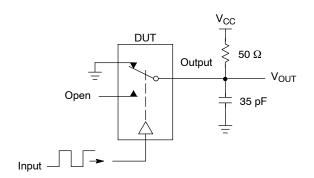


Figure 3. t_{ON}/t_{OFF}



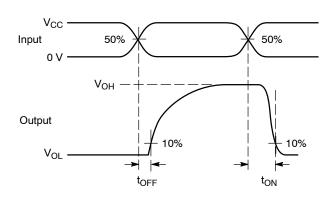
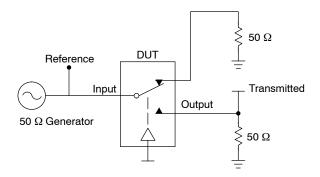


Figure 4. t_{ON}/t_{OFF}



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch. $V_{\rm ISO}$, Bandwidth and $V_{\rm ONL}$ are independent of the input signal direction.

$$\begin{split} &V_{ISO} = \text{Off Channel Isolation} = 20 \text{ Log}\left(\frac{V_{OUT}}{V_{IN}}\right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz} \\ &V_{ONL} = \text{On Channel Loss} = 20 \text{ Log}\left(\frac{V_{OUT}}{V_{IN}}\right) \text{ for } V_{IN} \text{ at } 100 \text{ kHz to } 50 \text{ MHz} \end{split}$$

Bandwidth (BW) = the frequency 3 dB below V_{ONL}

 V_{CT} = Use V_{ISO} setup and test to all other switch analog input/outputs terminated with 50 Ω

Figure 5. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V_{ONL}

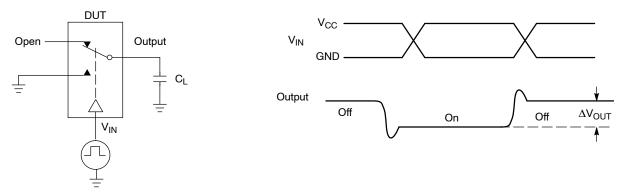


Figure 6. Charge Injection: (Q)

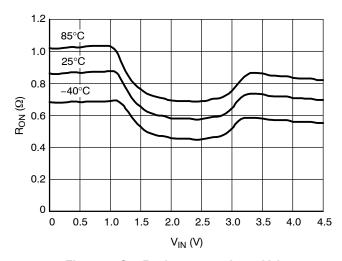


Figure 7. On-Resistance vs. Input Voltage @ V_{CC} = 4.3 V

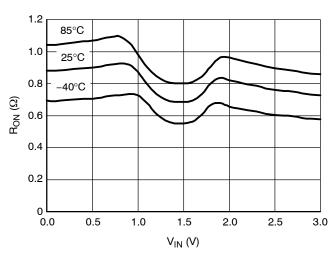


Figure 8. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 3.0 V

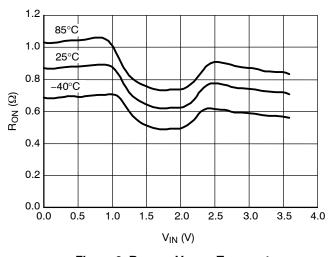


Figure 9. R_{ON} vs. V_{IN} vs. Temperature @ V_{CC} = 3.6 V

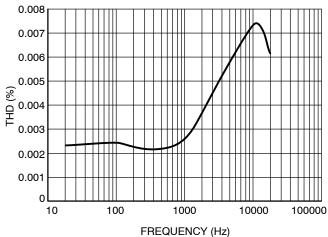


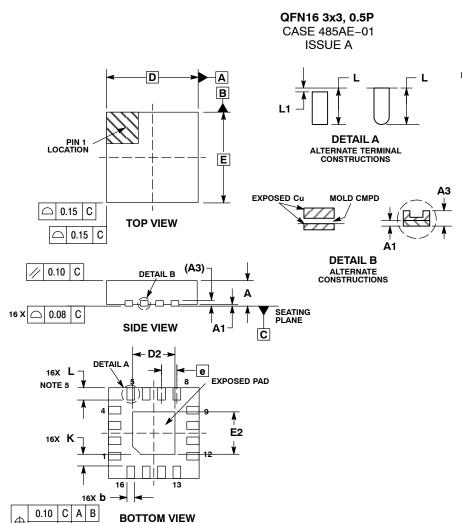
Figure 10. Total Harmonic Distortion vs. Frequency

ORDERING INFORMATION

		Devi	ce Nomenc	lature			
Device Order Number	Circuit Indicator	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Tape & Reel Size [†]
NLAS4783BMN1R2G	NL	AS	4783B	MN1	R2G	QFN (Pb-Free)	3000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED
 TERMINAL AND IS MEASURED BETWEEN
 0.25 AND 0.30 MM FROM TERMINAL.
 COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS.
 OUTLINE MEETS JEDEC DIMENSIONS PER
 MO-220, VARIATION VEED-6.

	MILLIMETERS					
DIM	MIN	NOM	MAX			
Α	0.80	0.90	1.00			
A1	0.00	0.03	0.05			
АЗ		0.20 REI	F			
b	0.18	0.25	0.30			
D		3.00 BS	С			
D2	1.25	1.40	1.55			
Е		3.00 BS	С			
E2	1.25	1.40	1.55			
е		0.50 BS	С			
Κ	0.20					
L	0.30	0.40	0.50			
L1	0.00		0.15			

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